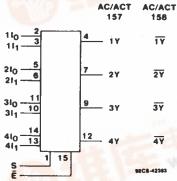


Data sheet acquired from Harris Semiconductor



Quad 2-Input Multiplexers

AC/ACT157 - Non-Inverting AC/ACT158 - Inverting

Type Features:

- Buffered inputs
- Typical propagation delay (AC/ACT158): 3.8 ns @ Vcc = 5 V, TA = 25° C, CL = 50 pF

FUNCTIONAL DIAGRAM

The RCA CD54/74AC157, -158 and CD54/74ACT157, -158 quad 2-input multiplexers use the RCA ADVANCED CMOS technology. Both circuits can select four bits of data from two sources under the control of a common select input (S). The Enable input (E) is active LOW. When E is HIGH, all of the outputs of the 158 are forced HIGH and in the 157, all of the outputs are forced LOW, regardless of all other input conditions.

The CD74AC/ACT157 and CD74AC/ACT158 are supplied in 16-lead dual-in-line plastic packages (E suffix) and in 16lead dual-in-line small-outline plastic packages (M suffix). Both package types are operable over the following temperature ranges: Commercial (0 to 70°C); Industrial (-40 to +85°C); and Extended Industrial/Military (-55 to +125°C).

The CD54AC157, -158 and CD54ACT157, -158, available in chip form (H suffix), are operable over the -55 to +125°C temperature range.

Family Features:

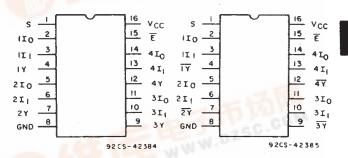
- Exceeds 2-kV ESD Protection MIL-STD-883, Method 3015
- SCR-Latchup-resistant CMOS process and circuit design
- Speed of bipolar FAST®/AS/S with significantly reduced power consumption
- Balanced propagation delays
- AC types feature 1.5-V to 5.5-V operation and balanced noise immunity at 30% of the supply.
- ± 24-mA output drive current
 - Fanout to 15 FAST® ICs
 - Drives 50-ohm transmission lines

FAST is a Registered Trademark of Fairchild Semiconductor Corp.

TRUTH TABLE

| | Select | ata | Output | | |
|--------|--------|---------------------------------|--------|-----|-----|
| Enable | Input | Inp | uts | 157 | 158 |
| Ē | S | S I ₀ I ₁ | | Υ | Y |
| Н | X | X | Х | L | Н |
| L | L | L | X | L | Н |
| L | L | н | х | Н | L |
| L | н | X | L | L | н |
| L | н | X | Н | н | L |

H = High level, L = Low level, X = Don't care



CD54/74AC/ACT157

CD54/74AC/ACT158

Technical Data

CD54/74AC157, CD54/74AC158 CD54/74ACT157, CD54/74ACT158

MAXIMUM RATINGS, Absolute-Maximum Values:

| DC SUPPLY-VOLTAGE (Vcc) | 0.5 to 6 V |
|--|-----------------------------------|
| DC INPUT DIODE CURRENT, l_{ik} (for $V_1 < -0.5 \text{ V}$ or $V_1 > V_{CC} + 0.5 \text{ V}$) | |
| DC OUTPUT DIODE CURRENT, I_{OK} (for $V_O < -0.5$ V or $V_O > V_{CC} + 0.5$ V) | ±50 mA |
| DC OUTPUT SOURCE OR SINK CURRENT per Output Pin, Io (for Vo > -0.5 V or Vo < Vo | $_{\infty}$ + 0.5 V) ±50 mA |
| DC V _{CC} or GROUND CURRENT (I _{CC} or I _{GND}) | ±100 mA* |
| POWER DISSIPATION PER PACKAGE (PD): | |
| For T _A = -55 to +100°C (PACKAGE TYPE E) | 500 mW |
| For T _A = +100 to +125°C (PACKAGE TYPE E) | ate Linearly at 8 mW/°C to 300 mW |
| For T _A = -55 to +70°C (PACKAGE TYPE M) | 400 mW |
| For T _A = +70 to +125°C (PACKAGE TYPE M) | rate Linearly at 6 mW/°C to 70 mW |
| OPERATING-TEMPERATURE RANGE (TA) | 55 to +125°C |
| STORAGE TEMPERATURE (Tstg) | 65 to +150°C |
| LEAD TEMPERATURE (DURING SOLDERING): | |
| At distance $1/16 \pm 1/32$ in. $(1.59 \pm 0.79$ mm) from case for 10 s maximum | +265°C |
| Unit inserted into PC board min. thickness 1/16 in. (1.59 mm) with solder contacting lea | id tips only +300°C |
| * For up to 4 outputs per devices add ± 06 m8 for each additional autout | |

^{*} For up to 4 outputs per device, add \pm 25 mA for each additional output.

RECOMMENDED OPERATING CONDITIONS:

For maximum reliability, normal operating conditions should be selected so that operation is always within the following ranges:

| OHADAOTEDIOTIO | LIN | IITS | LIMITE |
|---|------|------|--------|
| CHARACTERISTIC | MIN. | MAX. | צדואט |
| Supply-Voltage Range, Vcc*: | | | |
| (For T _A = Full Package-Temperature Range) | 1 | | + |
| AC Types | 1.5 | 5.5 | V |
| ACT Types | 4.5 | 5.5 | V |
| DC Input or Output Voltage, V ₁ , V ₀ | 0 | Vcc | V |
| Operating Temperature, T _A | -55 | +125 | °C |
| Input Rise and Fall Slew Rate, dt/dv | | | |
| at 1.5 V to 3 V(AC Types) | 0 | 50 | ns/V |
| at 3.6 V to 5.5 V(AC Types) | 0 | 20 | ns/V |
| at 4.5 V to 5.5 V(ACT Types) | 0 | 10 | ns/V |

^{*}Unless otherwise specified, all voltages are referenced to ground.

STATIC ELECTRICAL CHARACTERISTICS: AC Series

| | | | | AMBIENT TEMPERATURE (TA) - °C | | | | | | | |
|----------------------------------|-----------------|------------------------------|------------------------|-------------------------------|----------|----------|------|------------|------|-------------|-------|
| CHARACTERISTICS | | TEST CONDITIONS | | V _{cc} | + | +25 | | -40 to +85 | | -55 to +125 | |
| | | V, (V) | I _o (mA) | (V) | MIN. | MAX. | MIN. | MAX. | MIN. | MAX. | UNITS |
| High-Level Input | | | | 1.5 | 1.2 | _ | 1.2 | _ | 1.2 | _ | |
| Voltage | V _{IH} | | | 3 | 2.1 | _ | 2.1 | _ | 2.1 | <u> </u> | 7 v |
| | | | | 5.5 | 3.85 | _ | 3.85 | _ | 3.85 | _ | 1 |
| Low-Level Input | | | | 1.5 | | 0.3 | | 0.3 | _ | 0.3 | |
| Voltage | VIL | | | 3 | _ | 0.9 | | 0.9 | | 0.9 | V |
| | | | | 5.5 | | 1.65 | _ | 1.65 | _ | 1.65 | 1 |
| High-Level Output | | | -0.05 | 1.5 | 1.4 | | 1.4 | _ | 1.4 | _ | |
| Voltage | V _{он} | V _{IH} | -0.05 | 3 | 2.9 | <u> </u> | 2.9 | · — | 2.9 | | 1 |
| | | or | -0.05 | 4.5 | 4.4 | _ | 4.4 | ~~~ | 4.4 | _ | 1 |
| | | VIL | -4 | 3 | 2.58 | _ | 2.48 | _ | 2.4 | _ | 1 v |
| | | | -24 | 4.5 | 3.94 | _ | 3.8 | | 3.7 | _ | 1 |
| | | #, * { | -75 | 5.5 | _ | _ | 3.85 | | | _ | 1 |
| | | | -50 | 5.5 | _ | _ | _ | _ | 3.85 | _ | 1 |
| Low Level Output | | | 0.05 | 1.5 | <u> </u> | 0.1 | | 0.1 | _ | 0.1 | |
| Voltage | Vol | V _{IH} | 0.05 | 3 | _ | 0.1 | _ | 0.1 | _ | 0.1 | |
| | | or | 0.05 | 4.5 | _ | 0.1 | _ | 0.1 | _ | 0.1 | 1 |
| | | VIL | 12 | 3 | | 0.36 | _ | 0.44 | _ | 0.5 | 1 v |
| | | | 24 | 4.5 | | 0.36 | _ | 0.44 | _ | 0.5 | 1 |
| | | #, * { | 75 | 5.5 | | _ | _ | 1.65 | _ | _ | |
| | | { | 50 | 5.5 | _ | _ | _ | _ | _ | 1.65 | 1 1 |
| Input Leakage Current | l _t | V _∞ or GND | | 5.5 | _ | ±0.1 | | ±1 | | ±1 | μΑ |
| Quiescent Supply Current, MSI | lcc | V _{cc} or GND | 0 | 5.5 | _ | 8 | | 80 | | 160 | μΑ |

[#]Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

*Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

STATIC ELECTRICAL CHARACTERISTICS: ACT Series

| | | | | AMBIENT TEMPERATURE (TA) - °C | | | | | | | |
|---|-----------------|------------------------------|------------------------|-------------------------------|------|----------|------|-------|-------------|------|-------|
| CHARACTERISTICS | | TEST CO | NOITIONS | V _{cc} | +: | +25 -40 | | o +85 | -55 to +125 | | UNITS |
| | | V, (V) | l _o (mA) | (V) | MIN. | MAX. | MIN. | MAX. | MIN. | MAX. | |
| High-Level Input Voltage | ViH | | | 4.5 to 5.5 | 2 | _ | 2 | | 2 | _ | v |
| Low-Level Input Voltage | Vil | | | 4.5 to 5.5 | _ | 0.8 | _ | 0.8 | | 0.8 | v |
| High-Level Output | | ViH | -0.05 | 4.5 | 4.4 | _ | 4.4 | | 4.4 | | |
| Voltage | V _{OH} | or V _{IL} | -24 | 4.5 | 3.94 | <u> </u> | 3.8 | I | 3.7 | | V |
| | | #. * { | -75 | 5.5 | | | 3.85 | | | | |
| | | "' | -50 | 5.5 | _ | Ī — | | | 3.85 | | |
| Low-Level Output | | V _{IH} | 0.05 | 4.5 | _ | 0.1 | _ | 0.1 | | 0.1 |] |
| Voltage | Vol | or V _{IL} | 24 | 4.5 | _ | 0.36 | | 0.44 | | 0.5 | V |
| - | | #, * { | 75 | 5.5 | _ | - | _ | 1.65 | _ | | |
| | | " ' | 50 | 5.5 | _ | <u> </u> | | | | 1.65 | |
| Input Leakage Current | ŧ, | V _{cc} or GND | | 5.5 | | ±0.1 | | ±1 | | ±1 | μΑ |
| Quiescent Supply Current, MSI | lcc | V _{CC} or GND | 0 | 5.5 | | 8 | _ | 80 | | 160 | μΑ |
| Additional Quiescent Current per Input F TTL Inputs High 1 Unit Load | | V _{cc} -2.1 | | 4.5 to 5.5 | | 2.4 | _ | 2.8 | _ | 3 | mA |

[#]Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize nower dissination.

ACT INPUT LOADING TABLE

| | UNIT LOAD* | | | | |
|---------|------------|------|--|--|--|
| INPUT | 157 | 158 | | | |
| ł (All) | 0.37 | 0.37 | | | |
| Ē | 0.83 | 0.83 | | | |
| S | 1.33 | 1.33 | | | |

*Unit load is ΔI_{CC} limit specified in Static Characteristics Chart, e.g., 2.4 mA max. @ 25° C.

power dissipation.

* Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

SWITCHING CHARACTERISTICS: AC Series; t,, t, = 3 ns, C, = 50 pF

| | | | | AMBI | ENT TEMPE | RATURE (1 | Γ _A) - °C | |
|---------------------------------------|----------------|--------------------------------------|---|-----------------|----------------------|----------------|-----------------------|-------|
| CHARACTERISTICS | | SYMBOL | V _{cc} | -40 t | o +85 | -55 to | +125 | UNITS |
| | | | (V) | MIN. | MAX. | MIN. | MAX. |] |
| Propagation Delays: Data to Output | (157) | t _{PLH} t _{PHL} | 1.5 3.3* 5† | 3.2 2.2 | 97 10.8 7.7 | 3 2.1 | 106 11.9 8.5 | ns |
| Enable to Output | (157) | t _{РLН} t _{РНL} | 1.5 3.3 5 | 5.1 3.6 | 154 17.2 12.3 | 4.7 3.4 | 169 18.9 13.5 | ns |
| Select to Output | (157) | t _{PLH} t _{PHL} | 1.5 3.3 5 | 5.4 3.8 | 164 18.5 13.2 | 5.1 3.6 | 180 20.3 14.5 | ns |
| Data to Output | (158) | t _{PLH} t _{PHL} | 1.5 3.3 5 | 3 2.2 | 91 12.8 7.3 | _ 2.8 2 | 100 11.2 8 | ns |
| Enable to Output | (158) | t _{PLH} | 1.5 3.3 5 | 4.5 3.2 | 135 15.2 10.8 | 4.2 3 | 149 16.7 11.9 | ns |
| Select to Output | (158) | telн teнl | 1.5 3.3 5 | - 4.9 3.5 | 147 16.5 11.7 | 4.5 3.2 | 161 18.1 12.9 | ns |
| Power Dissipation Capacitance | (157) (158) | C _{PD} § | С _{РФ} § — 156 Тур. 156 Тур. 149 Тур. 149 Тур. | | 156 Typ. 149 Typ. | | | pF |
| Input Capacitance | | Cı | | | 10 | _ | 10 | pF |

SWITCHING CHARACTERISTIS: ACT Series; t,, t, = 3 ns, C_L = 50 pF

| | | 1 | | AM | BIENT TEM | PERATURE | (T _A) - °C | | |
|---------------------------------------|----------------|--------------------------------------|------------------------|----------------------|-----------|----------------------|------------------------|-------|--|
| CHARACTERISTICS | | SYMBOL | V _{cc} (V) | | o +85 | | +125 | UNITS | |
| | | | (*) | MIN. | MAX. | MIN. | MAX. | | |
| Propagation Delays: Data to Output | (157) | tpLH tpHL | 5† | 2.5 | 8.6 | 2.4 | 9.5 | ns | |
| Enable to Output | (157) | t _{РLН} t _{РНL} | 5 | 3.6 | 12.3 | 3.4 | 13.5 | ns | |
| Select to Output | (157) | tрін tрні | 5 | 3.8 | 13.2 | 3.6 | 14.5 | ns | |
| Data to Output | (158) | tецн tенц | 5 | 2.4 | 8.4 | 2.3 | 9.2 | ns | |
| Enable to Output | (158) | t _{PLH} t _{PHL} | 5 | 3.3 | 11.3 | 3.1 | 12.4 | ns | |
| Select to Output | (158) | telh tehl | 5 | 3.6 | 12.3 | 3.4 | 13.5 | ns | |
| Power Dissipation Capacitance | (157) (158) | C _{PD} § | _ | 156 Typ. 149 Typ. | | 156 Typ. 149 Typ. | | pF | |
| Input Capacitance | | Cı | | <u> </u> | 10 | _ | 10 | pF | |

*3.3 V: min. is @ 3.6 V max. is @ 3 V

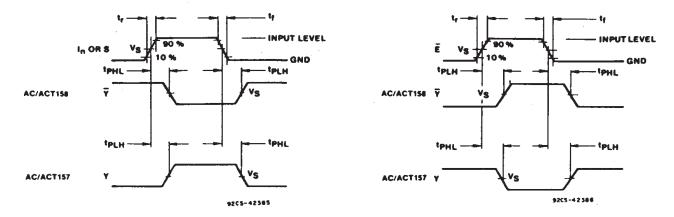
†5 V: min. is @ 5.5 V max. is @ 4.5 V §C_{PD} is used to determine the dynamic power consumption, per function.

For AC Series, $P_D = C_{PD}V_{CC}^2 f_i + \Sigma(C_L V_{CC}^2 f_o)$ For ACT Series, $P_D = C_{PD}V_{CC}^2 f_i + \Sigma(C_L V_{CC}^2 f_o) + V_{CC} \Delta I_{CC}$

where f_i = input frequency

fo = output frequency

 C_L = output load capacitance V_{CC} = supply voltage.



| | CD54/74AC | CD54/74ACT |
|------------------------------|---------------------|------------|
| Input Level | Vcc | 3 V |
| Input Switching Voltage, Vs | 0.5 V _{CC} | 1.5 V |
| Output Switching Voltage, Vs | 0.5 V _{CC} | 0.5 Vcc |

Fig. 3 - Inputs or select to output propagation delays.

Fig. 4 - Enable to output propagation delays.

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